**Product data sheet** 

### 1. General description

NPN medium power transistor series in a small SOT223 (SC-73) Surface-Mounted Device (SMD) plastic package.

**Table 1. Product overview** 

| Type number | Package  | NPN complement |          |
|-------------|----------|----------------|----------|
|             | Nexperia | JEITA          |          |
| BCP55       | SOT223   | SC73           | BCP52    |
| BCP55-10    |          |                | BCP52-10 |
| BCP55-16    |          |                | BCP52-16 |

### 2. Features and benefits

- · High current
- · Three current gain selections
- · High power dissipation capability

## 3. Applications

- · Linear voltage regulators
- Power management
- Low-side switches
- MOSFET drivers
- · Battery-driven devices
- Amplifiers

### 4. Quick reference data

Table 2. Quick reference data

| Symbol          | Parameter                 | Conditions  |     | Min | Тур | Max | Unit |
|-----------------|---------------------------|---|-----|-----|-----|-----|------|
| $V_{CEO}$       | collector-emitter voltage | open base   |     | -   | -   | 60  | V    |
| Ic              | collector current         |   |     | -   | -   | 1   | А    |
| I <sub>CM</sub> | peak collector current    | single pulse; t <sub>p</sub> ≤ 1 ms                                     |     | -   | -   | 2   | А    |
| h <sub>FE</sub> | DC current gain           |   |     |     |     |     |      |
|                 | BCP55                     | V <sub>CE</sub> = 2 V; I <sub>C</sub> = 150 mA T <sub>amb</sub> = 25 °C | [1] | 63  | -   | 250 |      |
|                 | BCP55-10                  |   | [1] | 63  | -   | 160 |      |
|                 | BCP55-16                  |   | [1] | 100 | -   | 250 |      |

[1] pulsed;  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ 



### 60 V, 1 A NPN medium power transistors

# 5. Pinning information

### Table 3. Pinning

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-------------|--------------------|----------------|
| 1   | В      | base        | 4                  | С              |
| 2   | С      | collector   |                    |                |
| 3   | E      | emitter     |                    | B—             |
| 4   | С      | collector   | ∃1 ∃2 ∃3           | Ė              |
|     |        |             |                    | sym123         |

# 6. Ordering information

### **Table 4. Ordering information**

| Type number | Package |  |         |  |  |  |  |  |
|-------------|---------|--|---------|--|--|--|--|--|
|             | Name    | Description  | Version |  |  |  |  |  |
| BCP55       | SC-73   | plastic surface-mounted package with increased heatsink; 4 leads | SOT223  |  |  |  |  |  |
| BCP55-10    |         |  |         |  |  |  |  |  |
| BCP55-16    |         |  |         |  |  |  |  |  |

# 7. Marking

### Table 5. Marking

| Type number | Marking code |
|-------------|--------------|
| BCP55       | BCP55        |
| BCP55-10    | BCP55 /10    |
| BCP55-16    | BCP55 /16    |

### 60 V, 1 A NPN medium power transistors

## 8. Limiting values

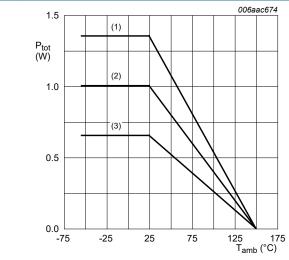
### **Table 6. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter                 | Conditions                          |                                     | Min | Max  | Unit |
|------------------|---------------------------|-------------------------------------|-------------------------------------|-----|------|------|
| $V_{CBO}$        | collector-base voltage    | open emitter                        | open emitter                        |     | 60   | V    |
| V <sub>CEO</sub> | collector-emitter voltage | open base                           |                                     | -   | 60   | V    |
| $V_{EBO}$        | emitter-base voltage      | open collector                      |                                     | -   | 5    | V    |
| I <sub>C</sub>   | collector current         |                                     |                                     | -   | 1    | А    |
| I <sub>CM</sub>  | peak collector current    | single pulse; t <sub>p</sub> ≤ 1 ms | single pulse; t <sub>p</sub> ≤ 1 ms |     | 2    | А    |
| I <sub>B</sub>   | base current              |                                     |                                     |     | 0.3  | А    |
| I <sub>BM</sub>  | peak base current         | single pulse; t <sub>p</sub> ≤ 1 ms | single pulse; t <sub>p</sub> ≤ 1 ms |     | 0.3  | А    |
| P <sub>tot</sub> | total power dissipation   | T <sub>amb</sub> ≤ 25 °C            | [1]                                 | -   | 0.65 | W    |
|                  |                           |                                     | [2]                                 | -   | 1.00 | W    |
|                  |                           |                                     | [3]                                 | -   | 1.35 | W    |
| Tj               | junction temperature      |                                     |                                     | -   | 150  | °C   |
| T <sub>amb</sub> | ambient temperature       |                                     |                                     | -55 | 150  | °C   |
| T <sub>stg</sub> | storage temperature       |                                     |                                     | -65 | 150  | °C   |

- Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

  Device mounted on an FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 1 cm<sup>2</sup>.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 6 cm<sup>2</sup>. [3]



- (1) FFR4 PCB, mounting pad for collector 6 cm<sup>2</sup>
- (2) FFR4 PCB, mounting pad for collector 1 cm<sup>2</sup>
- (3) FR4 PCB, standard footprint

Fig. 1. Power derating curves SOT223

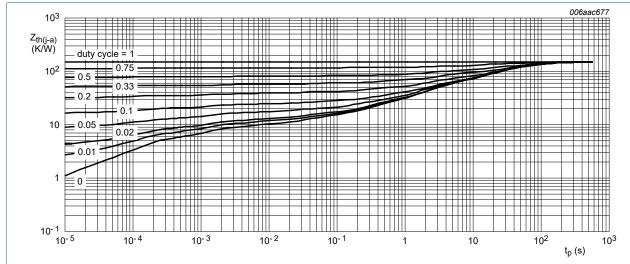
### 60 V, 1 A NPN medium power transistors

### 9. Thermal characteristics

**Table 7. Thermal characteristics** 

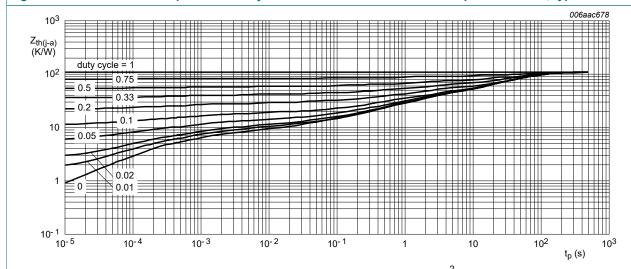
| Symbol                | Parameter  | Conditions  |     | Min | Тур | Max | Unit |
|-----------------------|--|-------------|-----|-----|-----|-----|------|
| R <sub>th(j-a)</sub>  | thermal resistance from junction to ambient      | in free air | [1] | -   | -   | 192 | K/W  |
|                       |  |             | [2] | -   | -   | 125 | K/W  |
|                       |  |             | [3] | -   | -   | 93  | K/W  |
| R <sub>th(j-sp)</sub> | thermal resistance from junction to solder point |             |     | -   | -   | 16  | K/W  |

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated; monting pad for collector 1 cm<sup>2</sup>.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated; monting pad for collector 6 cm<sup>2</sup>.



FR4 PCB, single-sided, tin-plated and standard footprint

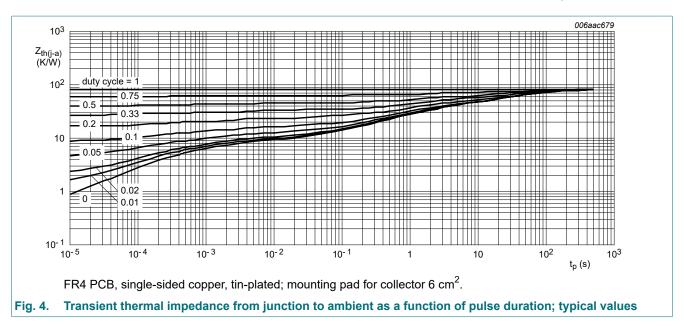
Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 1 cm<sup>2</sup>.

Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

### 60 V, 1 A NPN medium power transistors



### 60 V, 1 A NPN medium power transistors

## 10. Characteristics

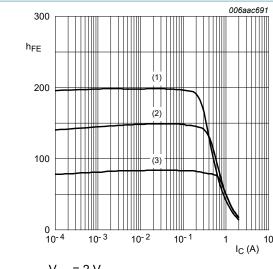
### **Table 8. Characteristics**

| Symbol               | Parameter                            | Conditions  |  | Min | Тур | Max | Unit |
|----------------------|--------------------------------------|---|--|-----|-----|-----|------|
| V <sub>(BR)CBO</sub> | collector-base<br>breakdown voltage  | I <sub>C</sub> = 100 μA; I <sub>E</sub> = 0 ; T <sub>amb</sub> = 25 °C                                |  | 60  | -   | -   | V    |
| V <sub>(BR)CEO</sub> | collector-emitter breakdown voltage  | $I_C = 2 \mu A; I_B = 0 A; T_{amb} = 25 °C$ 60  |  |     | -   | _   | V    |
| V <sub>(BR)EBO</sub> | emitter-base<br>breakdown voltage    | I <sub>C</sub> = 0 A; I <sub>E</sub> = 100 μA   |  | 5   | -   | -   | V    |
| I <sub>CBO</sub>     | collector-base                       | V <sub>CB</sub> = 30 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C                                |  | -   | -   | 100 | nA   |
|                      | cut-off current                      | V <sub>CB</sub> = 30 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C                                 |  | -   | -   | 10  | μA   |
| I <sub>EBO</sub>     | emitter-base cut-off current         | V <sub>EB</sub> = 5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C                                 |  | -   | -   | 100 | nA   |
| h <sub>FE</sub>      | DC current gain                      |   |  |     |     | '   |      |
|                      | BCP55                                | V <sub>CE</sub> = 2 V; I <sub>C</sub> = 5 mA; T <sub>amb</sub> = 25 °C                                | [1]                                    | 63  | -   | -   |      |
|                      |                                      | V <sub>CE</sub> = 2 V; I <sub>C</sub> = 150 mA; T <sub>amb</sub> = 25 °C                              | [1]                                    | 63  | -   | 250 |      |
| BCP55-               |                                      | V <sub>CE</sub> = 2 V; I <sub>C</sub> = 500 mA; T <sub>amb</sub> = 25 °C                              | [1]                                    | 40  | -   | -   |      |
|                      | BCP55-10                             | V <sub>CE</sub> = 2 V; I <sub>C</sub> = 5 mA; T <sub>amb</sub> = 25 °C                                | [1]                                    | 63  | -   | -   |      |
|                      |                                      | V <sub>CE</sub> = 2 V; I <sub>C</sub> = 150 mA; T <sub>amb</sub> = 25 °C                              | [1]                                    | 63  | -   | 160 |      |
|                      |                                      | V <sub>CE</sub> = 2 V; I <sub>C</sub> = 500 mA; T <sub>amb</sub> = 25 °C                              | [1]                                    | 40  | -   | -   |      |
| ВС                   | BCP55-16                             | V <sub>CE</sub> = 2 V; I <sub>C</sub> = 5 mA; T <sub>amb</sub> = 25 °C                                | [1]                                    | 63  | -   | -   |      |
|                      |                                      | V <sub>CE</sub> = 2 V; I <sub>C</sub> = 150 mA; T <sub>amb</sub> = 25 °C                              | [1]                                    | 100 | -   | 250 |      |
|                      |                                      | V <sub>CE</sub> = 2 V; I <sub>C</sub> = 500 mA; T <sub>amb</sub> = 25 °C                              | [1]                                    | 40  | -   | -   |      |
| h <sub>FE</sub>      | DC current gain                      | V <sub>CE</sub> = 2 V; I <sub>C</sub> = 5 mA; T <sub>amb</sub> = 25 °C                                | [1]                                    | 63  | -   | -   |      |
| h <sub>FE</sub>      | DC current gain                      | V <sub>CE</sub> = 2 V; I <sub>C</sub> = 500 mA; T <sub>amb</sub> = 25 °C                              | [1]                                    | 40  | -   | -   |      |
| V <sub>CEsat</sub>   | collector-emitter saturation voltage | I <sub>C</sub> = 500 mA; I <sub>B</sub> = 50 mA; T <sub>amb</sub> = 25 °C                             | 52 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 |     | -   | 0.5 | V    |
| V <sub>BE</sub>      | base-emitter voltage                 | V <sub>CE</sub> = 2 V; I <sub>C</sub> = 500 mA; T <sub>amb</sub> = 25 °C                              | [1]                                    | -   | -   | 1   | V    |
| C <sub>c</sub>       | collector capacitance                | V <sub>CB</sub> = 10 V; I <sub>E</sub> = i <sub>e</sub> = 0 A; f = 1 MHz;<br>T <sub>amb</sub> = 25 °C |  | 6   | -   | pF  |      |
| f <sub>T</sub>       | transition frequency                 | V <sub>CE</sub> = 5 V; I <sub>C</sub> = 50 mA; f = 100 MHz;<br>T <sub>amb</sub> = 25 °C               | 100                                    | 180 | -   | MHz |      |

<sup>[1]</sup> pulsed;  $t_p \le 300 \ \mu s; \ \delta \le 0.02$ 

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### 60 V, 1 A NPN medium power transistors



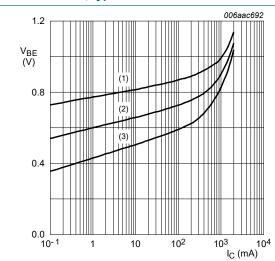
$$V_{CE} = 2 V$$

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb}$$
 = 25 °C

(3) 
$$T_{amb} = -55$$
 °C

Fig. 5. DC current gain as a function of collector current; typical values

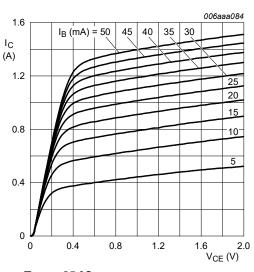


$$V_{CE} = 2 V$$

(1) 
$$T_{amb} = -55 \, ^{\circ}C$$

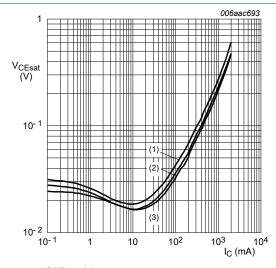
(3) 
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 7. Base-emitter voltage as a function of collector current; typical values



 $T_{amb}$  = 25 °C

Fig. 6. Collector current as a function of collectoremitter voltage; typical values



(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

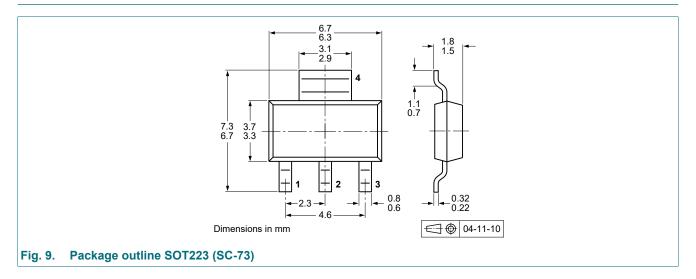
(2) 
$$T_{amb}$$
 = 25 °C

(3) 
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 8. Collector-emitter saturation voltage as a function of collector current; typical values

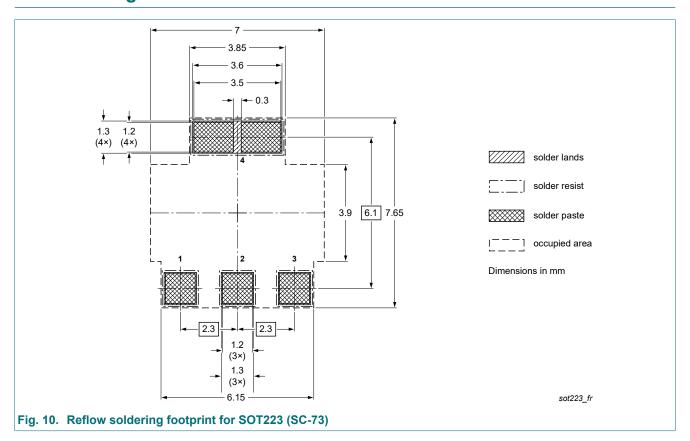
### 60 V, 1 A NPN medium power transistors

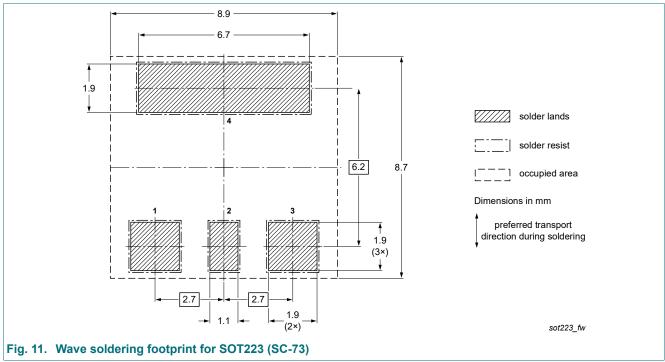
# 11. Package outline



### 60 V, 1 A NPN medium power transistors

## 12. Soldering





### 60 V, 1 A NPN medium power transistors

# 13. Revision history

### Table 9. Revision history

| Tubic 5. Itevision matery |                       |  |               |   |  |  |  |
|---------------------------|-----------------------|--|---------------|---|--|--|--|
| Data sheet ID             | Release date          | Data sheet status  | Change notice | Supersedes  |  |  |  |
| BCP55_SER v.9             | 20220701              | Product data sheet   | -             | BCP55_BCX55_BC55PA v.8                                  |  |  |  |
| Modifications:            | package. Package info | ata sheet describing several packages reduced to series data sheets per . information removed. changed to non-automotive qualification. Please refer to nexperia.com for ve (-Q) product alternative(s). |               |   |  |  |  |
| BCP55_BCX55_BC55PA v.8    | 20111024              | Product data sheet   | -             | BC637_BCP55_BCX55 v.7                                   |  |  |  |
| BC637_BCP55_BCX55 v.7     | 20070625              | Product data sheet   | -             | BC637_BCP55_BCX55 v.6                                   |  |  |  |
| BC637_BCP55_BCX55 v.6     | 20050218              | Product data sheet   | CPCN200405029 | BC635_637_639 v.4<br>BCP54_55_56 v.5<br>BCX54_55_56 v.4 |  |  |  |
| BC635_637_639 v.4         | 20011010              | Product Specification  | -             | BC635_637_639 v.3                                       |  |  |  |
| BCP54_55_56 v.5           | 20030206              | Product Specification  | -             | BCX54_55_56 v.4   |  |  |  |
| BCX54_55_56 v.4           | 20011010              | Product Specification  | -             | BCX54_55_56 v.3   |  |  |  |

# 60 V, 1 A NPN medium power transistors

### 14. Legal information

#### **Data sheet status**

| Document status [1][2]         | Product<br>status [3] | Definition  |
|--------------------------------|-----------------------|---|
| Objective [short] data sheet   | Development           | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification         | This document contains data from the preliminary specification.                       |
| Product [short]<br>data sheet  | Production            | This document contains the product specification.                                     |

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <a href="https://www.nexperia.com">https://www.nexperia.com</a>.

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